Supporting Information

Self-templated formation of hierarchically yolk-shell-structured

ZnS/NC dodecahedra with superior lithium storage properties

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Fig. S2 XPS spectra of NC: (a) survey, (b) C1s, and (c) N1s.



Fig. S3 TG curve of ZnS(72 h)/NC.



Fig. S4 SEM images of (a) ZIF-8, (b) ZnS(12 h)@ZIF-8, (c) ZnS(24 h)@ZIF-8, (d) ZnS(48 h)@ZIF-8, (e) ZnS(72 h)@ZIF-8, (f) ZnS(84 h)@ZIF-8, and (g) ZnS(96 h)@ZIF-8. The scale bar represents 1 μ m.



Fig. S5 TEM images of (a) ZIF-8, (b) ZnS(12 h)@ZIF-8, (c) ZnS(24 h)@ZIF-8, (d) ZnS(48 h)@ZIF-8, (e) ZnS(72 h)@ZIF-8, (f) ZnS(84 h)@ZIF-8, and (g) ZnS(96 h)@ZIF-8. The scale bar represents 1 μ m.



Fig. S6 SEM and TEM images of (a, b) NC, (c, d) ZnS(12 h)/NC, (e, f) ZnS(24 h)/NC, (g, h) ZnS(48 h)/NC, (i, j) ZnS(72 h)/NC, (k, l) ZnS(84 h)/NC, and (m, n) ZnS(96 h)/NC. The scale bar represents 1 μ m.



Fig. S7 (a) N₂ adsorption-desorption isotherms (77 K) and (b, c) pore size distributions of NC and ZnS(x h)/NC ($x = 12^{-96}$).



Fig. S8 Cyclic voltammetry curves of (a) NC, (b) ZnS(12 h)/NC, (c) ZnS(24 h)/NC, (d) ZnS(48 h)/NC, (e) ZnS(84 h)/NC, and (f) ZnS(96 h)/NC.



Fig. S9 Galvanostatic discharge-charge voltage profiles at 100 mA g^{-1} of (a) NC, (b) ZnS(12 h)/NC, (c) ZnS(24 h)/NC, (d) ZnS(48 h)/NC, (e) ZnS(84 h)/NC, and (f) ZnS(96 h)/NC.



Fig. S10 Cycling performance and coulombic efficiency in the voltage window of $0.01^{-3.0}$ V vs. Li/Li⁺ at 200 mA g⁻¹ of (a) NC, (b) ZnS(12 h)/NC, (c) ZnS(24 h)/NC, (d) ZnS(48 h)/NC, (e) ZnS(84 h)/NC, and (f) ZnS(96 h)/NC.



Fig. S11 Impedance spectrum as-prepared sample. (a) NC, (b) ZnS(12 h)/NC, (c) ZnS(24 h)/NC, (d) ZnS(48 h)/NC, (e) ZnS(72 h)/NC (inset: the plot of Z_{re} vs. the reciprocal root square of the low angular frequencies ($\omega^{-1/2}$)), (f) ZnS(84 h)/NC, (g) ZnS(96 h)/NC.



Fig. S12 (a) SEM and (b) TEM images of the ZnS(72 h)/NC electrode after the cycles.



Fig. S13 (a) CV curves of ZnS(72 h)/NC at different scan rates; (b) Determination of the *b*-value by plotting the linear relationship between log(i) and log(v); (c) Charge contribution ratios from capacitive and diffusion-controlled process at various scan rates; (d) Separation of the capacitive and diffusion-controlled currents at a scan rate of 0.6 mV s⁻¹.

Materials	Specific capacity (mAh g ⁻¹)	Cycle number	Current density (mA g ⁻¹)	Reference	
ZnS(72 h)/NC	757	200	200	this work	
	~500	1000	2000		
ZnS-C/graphene	571	120	1000	S1	
ZnS/graphene	570	200	200	S2	
ZnS-rGO	776	100	100	S3	
ZnS@NC	690	100	100	S4	
ZnS/NPC	1067	200	100	S5	
ZnS NR@HCP	840	300	600	S6	
ZnS/C NPs	506	600	500	S7	
ZnS-QDS@NC	506	300	840	S8	
ZnS-C	530	600	100	S9	
ZnS/C	570	150	100	S10	
ZnS/C	741	300	100	S11	
ZnS-C	868	300	1000	S12	
ZnS/C	482	300	400	S13	
ZnS/nano-cell	1134	100	500	S14	
Zn-Co-S@N-C	668	300	1000	S15	

Table S1 Electrochemical performances of ZnS-based anode materials for LIBs.

Table S2 Electrochemical impedance fitting parameters of ZnS(72 h)/NC.

Cycles	<i>R</i> _s (Ω)	<i>R</i> _{ct} (Ω)	σ (Ω S ^{-1/2})	D _{Li} ⁺ (cm ² s ⁻¹)
before test	7	93	179	9.86 × 10 ⁻¹³
after cycles	13	15	73	5.9 × 10 ⁻¹²

The diffusion coefficients (*D*) of Li⁺ ions can be calculated from the following formula of $D = R^2 T^2 / (2A^2 n^4 F^4 C^2 \sigma^2)$ where *A* is the surface area of electrode, *n* is the number of electrons per molecule attending electronic transfer reaction, *F* is the Faraday constant, *C* is the concentration of Li⁺ in the electrode, σ is the slope of the line $Z' \sim \omega^{-1/2}$, *R* is the gas constant, and *T* is ambient temperature. The *F* and *R* values are 96500 C mol⁻¹ and 8.314 J K⁻¹ mol⁻¹, respectively.

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